

## Photocoupler



### K4N35 • K4N36 • K4N37

These Photocouplers consist of a Gallium Arsenide Infrared Emitting Diode and a Silicon NPN Phototransistor in 6-pin package.

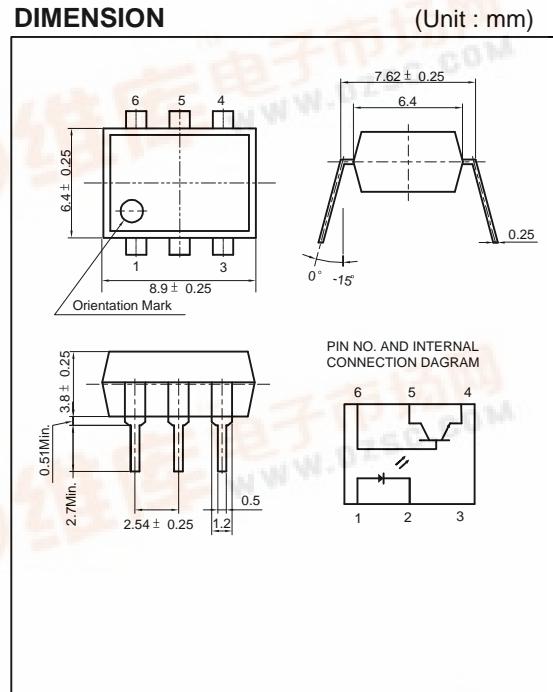
#### FEATURES

- Switching Time - Typ. 3 $\mu$ s
- Collector-Emitter Voltage : Min.30V
- Current Transfer Ratio : Typ.100% (at If=10mA, Vce=10V)
- Electrical Isolation Voltage : AC2500Vrms
- UL Recognized File No. E107486

#### APPLICATIONS

- Interface between two circuits of different potential
- Vending Machine, Voltage Regulator
- Traffic Controller System
- Programmable Controller

#### DIMENSION



#### MAXIMUM RATINGS

(Ta=25 °C)

	Parameter	Symbol	Rating	Unit
Input	Forward Current	If	60	mA
	Reverse Voltage	V <sub>R</sub>	5	V
	Peak Forward Current <sup>*1</sup>	I <sub>FP</sub>	3	A
	Power Dissipation	P <sub>D</sub>	70	mW
Output	Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	35 <sup>*4</sup>	V
	Emitter-Collector Breakdown Voltage	BV <sub>ECO</sub>	6	V
	Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	70	V
	Collector Current	I <sub>C</sub>	50	mA
	Collector Power Dissipation	P <sub>C</sub>	150	mW
Input to Output Isolation Voltage <sup>*2</sup>		V <sub>iso</sub>	AC2500	V <sub>rms</sub>
Storage Temperature		T <sub>stg</sub>	-55~+125	
Operating Temperature		T <sub>opr</sub>	-30~+100	
Lead Soldering Temperature <sup>*3</sup>		T <sub>sol</sub>	260	
Total Power Dissipation		P <sub>tot</sub>	200	mW

\*1. Input current with 100 $\mu$ s pulse width, 1% duty cycle

\*2. Measured at RH=40~60% for 1min

\*3. 1/16 inch form case for 10sec

\*4. Customer Option

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### ELECTRO-OPTICAL CHARACTERISTICS

(Ta=25°C, unless otherwise noted)

Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit.
Input	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =10mA	-	1.15	1.30	V
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> =5V	-	-	10	μA
	Capacitance	C <sub>T</sub>	V=0, f=1MHz	-	30	-	pF
Output	Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> =1mA	35	-	-	V
	Emitter-Collector Breakdown Voltage	BV <sub>ECO</sub>	I <sub>E</sub> =0.1mA	6	-	-	V
	Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	I <sub>C</sub> =0.1mA	70	-	-	V
	Collector Dark Current	I <sub>CEO</sub>	I <sub>F</sub> =0, V <sub>CE</sub> =10V	-	-	50	nA
	Capacitance	C <sub>CE</sub>	V <sub>CE</sub> =0, f=1MHz	-	10	-	pF
Coupled	Current Transfer Ratio <sup>*5</sup>	CTR	I <sub>F</sub> =10mA, V <sub>CE</sub> =10V	100	-	-	%
	Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	I <sub>F</sub> =10mA, I <sub>C</sub> =0.5mA	-	0.15	0.3	V
	Input-Output Capacitance	C <sub>IO</sub>	V=0, f=1MHz	-	1	-	pF
	Input-Output Isolation Resistance	R <sub>IO</sub>	RH=40~60%, V=500V	-	10 <sup>11</sup>	-	
	Rise Time	tr	V <sub>CC</sub> =10V, R <sub>L</sub> =100Ω	-	3	10	
	Fall Time	tf		-	3	10	

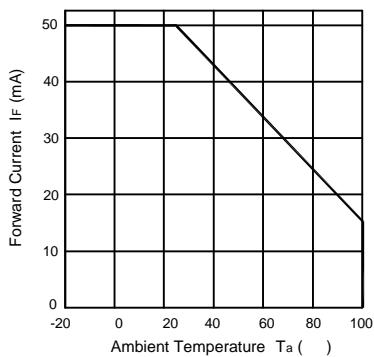
\*5. CTR=(I<sub>C</sub>/I<sub>F</sub>) X 100 (%)

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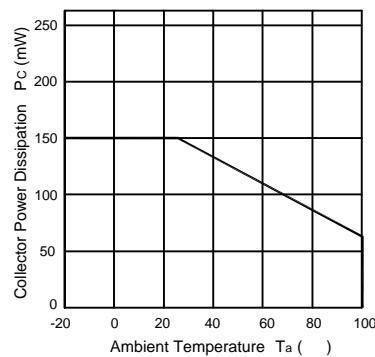
**KODENSHI**

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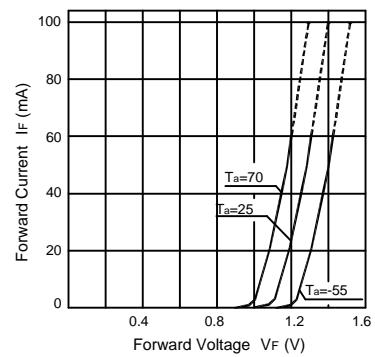
**Forward Current vs.  
Ambient Temperature**



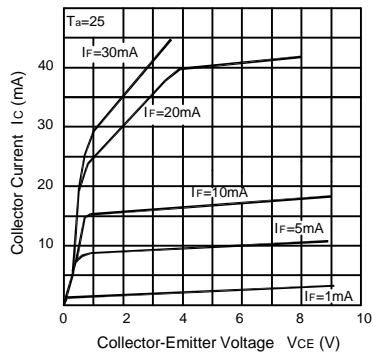
**Collector Power Dissipation vs.  
Ambient Temperature**



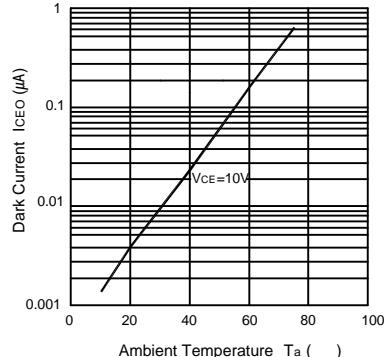
**Forward Current vs.  
Forward Voltage**



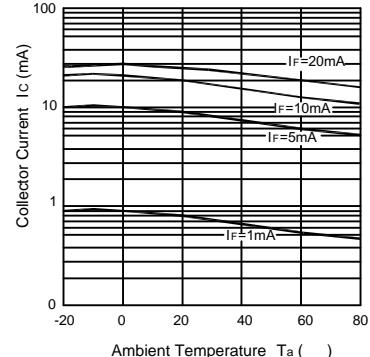
**Collector Current vs.  
Collector-Emitter Voltage**



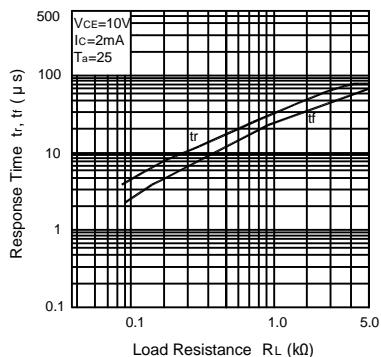
**Dark Current vs.  
Ambient Temperature**



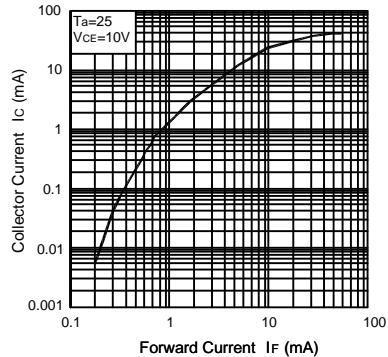
**Collector Current vs.  
Ambient Temperature**



**Response Time vs.  
Load Resistance**



**Collector Current vs.  
Forward Current**



**Switching Time Test Circuit**

